**ON Semiconductor** 

Is Now

# Onsemi

To learn more about onsemi<sup>™</sup>, please visit our website at <u>www.onsemi.com</u>

onsemi and ONSEMI. and other names, marks, and brands are registered and/or common law trademarks of Semiconductor Components Industries, LLC dba "onsemi" or its affiliates and/or subsidiaries in the United States and/or other countries. onsemi owns the rights to a number of patents, trademarks, copyrights, trade secrets, and other intellectual property. A listing of onsemi product/patent coverage may be accessed at www.onsemi.com/site/pdf/Patent-Marking.pdf. onsemi reserves the right to make changes at any time to any products or information herein, without notice. The information herein is provided "as-is" and onsemi makes no warranty, representation or guarantee regarding the accuracy of the information, product factures, availability, functionality, or suitability of its products for any particular purpose, nor does onsemi assume any liability arising out of the application or use of any product or circuit, and specifically disclaims any and all liability, including without limitation special, consequential or incidental damages. Buyer is responsible for its products and applications using onsemi products, including compliance with all laws, regulations and asfety requirements or standards, regardless of any support or applications information provided by onsemi. "Typical" parameters which may be provided in onsemi data sheets and/or by customer's technical experts. onsemi products and actal performance may vary over time. All operating parameters, including "Typicals" must be validated for each customer application by customer's technical experts. onsemi products are not designed, intended, or authorized for use as a critical component in life support systems or any FDA Class 3 medical devices or medical devices with a same or similar classification in a foreign jurisdiction or any devices intended for implantation in the human body. Should Buyer purchase or use onsemi products for any such unintended or unauthorized application, Buyer shall indemnify and hold onsemi and its officers, employees, subsidiari

# Isolated Precision Regulation of a Single 1.8 Volt Output from a Universal Line Input

Prepared by: Jason Hansen ON Semiconductor

#### INTRODUCTION

The following Application Note describes an off–line switching power supply utilizing a precision programmable reference to regulate a 1.8 volt output. The center of the app note is the MC33363B, a monolithic SMPS controller with a 700 volt power switch, and the NCP100, a sub–one volt precision programmable reference. The system design and analysis will be described in detail.

The design requirements are for a universal off-line converter with a 1.8 volt, 1.0 ampere single output with less than 50 millivolts ripple and operates at 100 kHz. Most of the components selected are surface mount. This design is separated into the generic circuit of the off-line converter and the feedback network.



#### ON Semiconductor<sup>™</sup>

http://onsemi.com

#### **APPLICATION NOTE**

#### Generic Off-Line Conversion Circuit

To reduce the total number of components and thus minimize circuit board area, an SMPS controller with an integrated power switch is selected. With the low output power requirement, the MC33363B is selected as the control and power switch IC. The MC33363B contains an externally programmable frequency and current limit, internal startup circuit and can handle up to 8 watts of output power.

The basic off-line conversion circuit is illustrated in Figure 1. The line input is filtered through the EMC circuit then rectified and filtered. The rectified voltage is converted to a lower voltage via the transformer and the MC33363B. The secondary of the transformer is rectified to a DC voltage and filtered. The output voltage controls the duty cycle of the switcher via the isolated feedback network. The calculated values are a starting point and do not replace bench testing.

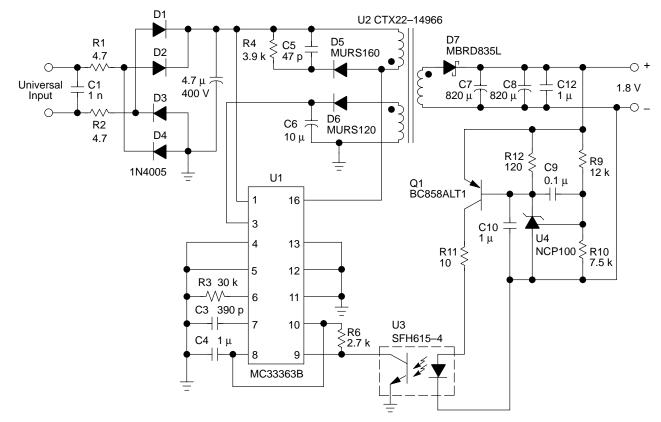


Figure 1. MC33363B Basic Flyback Circuit Schematic

Since the power level is low, an RC EMC filter is utilized. The RC filter is not as efficient as an LC, but it uses less board area and will cost less. 1N4005 600 volt fast diodes provide the full wave rectification of the AC input. The bulk capacitor is the filter. The selection of the capacitor is determined from three factors: input voltage, ripple current and maximum output ripple. The equations for each are as follows.

$$Vdc = Vac \cdot \sqrt{2}$$
 (eq. 1)

Irms = 
$$\sqrt{\text{Ipk}^2 \cdot \frac{D}{3}}$$
 (Discontinuous (eq. 2)

$$Cin = \frac{k \cdot Pin (AV)}{f \cdot (Vripple (p-p))^2}$$
(eq. 3)

$$Pin = \frac{Pout}{\eta}$$
 (eq. 4)

Where k is 1 for AC inputs the peak to peak ripple is 6.0 volts and  $\eta$  is estimated to be 70% with the low power level of the board and the RC input filter. Solving for the equations above and using 50% for the maximum duty cycle, Vdc maximum is 375 volts, Vdc minimum is 120 volts, Ipeak and Irms are solved for in the transformer calculations, Pin is 3.2 watts, and Cbulk is 0.9 uF.<sup>(1)</sup>

The transformer converts the rectified line voltage to the output voltage and is controlled by the MC33363B. To design the transformer, the following data is necessary. Vdc minimum is 100 volts (allowing for bulk voltage ripple and power switch voltage drop), the frequency is 100 kHz, the maximum duty cycle of the power switch and the reset time for the secondary are both 45% to maintain discontinuous conduction, and the secondary diode forward voltage drop is 0.45 volts (estimated).

$$Psec = (Vout + Vdiode) \cdot lout$$
 (eq. 5)

$$Pin = \frac{\frac{1}{2} (Vdc \cdot Ton)^2}{Lpri \cdot T} , or \qquad (eq. 6)$$

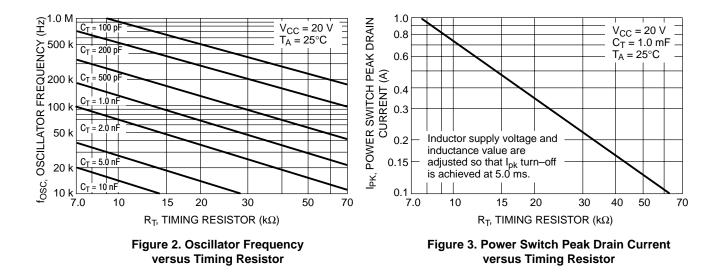
$$Lpri = \frac{\frac{1}{2} (Vdc \cdot Ton)^2}{Pin \cdot T}$$
 (eq. 7)

lpeak = 
$$\sqrt{2 \cdot P \cdot \frac{T}{L}}$$
 (eq. 8)

$$\frac{\text{Lpri}}{\text{Lsec}} = \left(\frac{\text{Np}}{\text{Ns}}\right)^2 \quad (\text{eq. 9})$$

For the primary side of the transformer, Lpri is 3.16 mH, Ipeak is 142 milliamperes, ton is 4.5 usec and Irms is 55 milliamperes–rms. For the secondary, Psec is 2.25 watts, L is 2.28 uH, Ipeak is 4.44 amperes and Irms is 1.72 amperes–rms. The turns ratio is 37.2. The auxiliary winding is set to 12 volts and 10 milliamperes. Using the secondary turns ratio, the auxiliary turns ratio is calculated as 6.6 in reference to the primary.

With the peak primary current and the frequency determined, the components surrounding the MC33363B can be selected. Referring to Figures 2 and 3, RT will be set to 30 k Ohms and CT will be set to 390 pF. The Over Voltage Protection, pin 11, will not be used. Its main function is for loss of optocoupler protection. Pin 8, the reference voltage, requires a 1.0 uF ceramic capacitor for stability. The voltage compensation and voltage feedback, pins 9 and 10, will be covered in the feedback section of this document. The Vcc pin requires a 10 uF capacitor for stability.



A snubber is required across the primary winding because of the leakage inductance. An RCD snubber is implemented. The diode will be an MURS160 ultrafast diode. The resistor and capacitor are dependent upon the leakage inductance of the primary windings of the transformer. Preliminary values of the resistor and capacitor are derived from the following equations. The final values will be determined on the bench with an examination of the trade–offs between system efficiency and peak voltage.

Vreflect = (Vout + Vdiode) 
$$\cdot \frac{Np}{Ns}$$
 (eq. 10)

$$R = \frac{2 \cdot Vmax \cdot (Vmax - (Vout + Vdiode) \cdot \frac{Np}{Ns})}{Lleak \cdot Ip^2 \cdot freq}$$
(eq. 11)

$$C = \frac{Vmax}{Vcr \cdot R \cdot freq}$$
 (eq. 12)

See AND8023/D page 7 for further information on equations 11 and 12.<sup>(2)</sup>

Vmax is the desired peak voltage on the power switch minus the bulk voltage, Vcr is the clamping ripple usually 20 V, and freq is the switching frequency of the MC33363B.

Most of the values necessary to calculate the secondary components are complete. To select the diode, the secondary current peak, the blocking voltage and the forward voltage drop are the main criteria. Ripple current from the transformer, the output voltage and the output ripple current are the criteria to select the output capacitors.

$$Vblock = Vout + \left(Vdc \cdot \frac{Ns}{Np}\right) \qquad (eq. 13)$$

$$C = \frac{1}{\text{Vripple} \cdot \text{freq}} \qquad (\text{eq. 14})$$

Utilizing the above equations and previous calculations, the diode needs to be rated at a minimum of 13 volts and 4.44 amperes. The MBRD835L is selected as the Schottky diode. The typical forward diode drop is 0.40 volts at 4.0 amperes. Rubycon capacitor YXG 6.3 volts 820 uF is chosen for the output filter. The voltage on the output capacitor needs to be rated twice the output voltage for safety. The rated maximum allowable ripple current of the capacitors is 0.865 amperes, so 2 capacitors in parallel will be used. A 1.0 uF ceramic capacitor will also be used in parallel with the aluminum electrolytics for fast transient response.

Equations 13 and 14 are used to calculate the auxiliary winding values. The auxiliary winding diode is an ultrafast recovery surface mount, MURS120. The diode is rated for 1 ampere and 200 volts blocking. The typical forward voltage drop is 0.6 volts. The higher forward voltage drop is acceptable due to the lower power requirements of the auxiliary versus the secondary output. The auxiliary winding filter is the capacitor on the  $V_{CC}$  pin.

#### Feedback Network

With the low voltage output requirement, a programmable precision reference with a low operating voltage is essential. Isolated feedback networks provide an additional challenge since optoisolator diode forward voltages remain at 1.25 volts. With a conventional circuit using the TL431 and TLV431, the lowest ideal power supply output voltages are 3.75 and 2.5 volts respectively. If the reference operating voltage range is reduced to 0.9 volts, the minimum output voltage is lowered to 2.15 volts. See Figure 4 for the circuit schematic.

This reduction is significant but will not satisfy a 1.8 volt output. By adding a resistor and PNP transistor, the reference voltage is reduced to the emitter–base voltage drop plus the programmable reference operating voltage. With the conventional TLV431 the minimum operating voltage is reduced to 1.95 volts. With the reduced reference voltage available in the NCP100, the minimum operating voltage is 1.6 volts. See Figure 5 for the circuit schematic. Figure 6 illustrates the output voltage ranges between the TL431, TLV431 and NCP100.

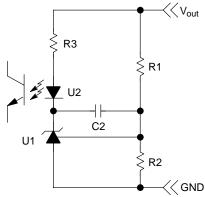


Figure 4. Traditional Isolated Feedback Network

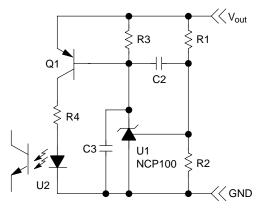


Figure 5. 1.8 Volt Isolated Feedback Network

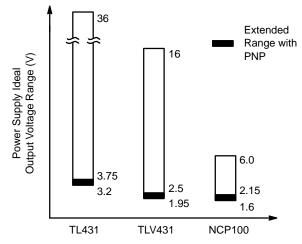


Figure 6. Power Supply Output Voltage Range Comparison for Programmable Precision References

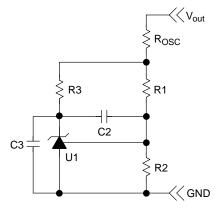


Figure 5 illustrates an additional 1.0 uF capacitor, C3, which is required for normal operation of the NCP100. Bandwidth concerns are raised when a capacitor is placed from the cathode to anode of the precision reference. Since the PNP transistor is used to drive the optocoupler, the cathode current of the NCP100 is amplified by the beta of the transistor therefore minimizing the effects of C3. R3 is a factor in the overall gain of the feedback network and R4 limits the current into the diode of the optocoupler. The roll–off frequency of the feedback network is related to R1 and C2 only. Figure 7 shows the circuit schematic, the gain and the phase of the TLV431 and the NCP100 with and without the PNP.

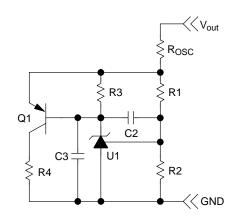
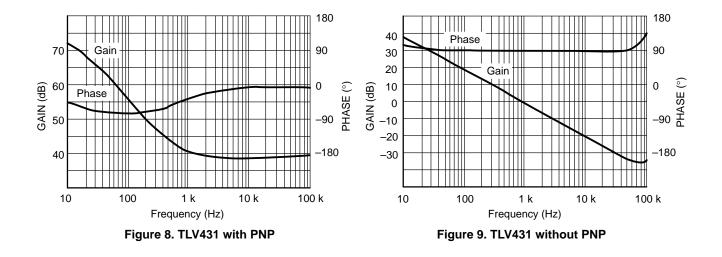
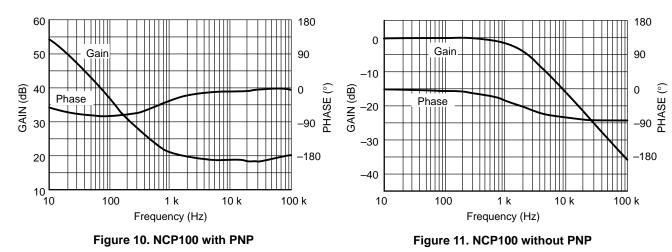


Figure 7. Schematics for Gain and Phase Comparison of TLV431 and NCP100 Note: C3 only for NCP100





The values for the components in Figure 7 are as follows. Rosc = 12 Ohms, R1 = 12 k Ohms, R2 is adjustable dependant upon U1, R3 and R4 = 100 Ohms, C2 = 0.01 uF, and C3 = 1.0 uF.

The open loop gain and phase test injects the oscillator signal across Rosc. The reference voltage is measured between Rosc and R1 to ground. The test voltage is measured at the collector of Q1 for the PNP circuit or at the cathode of U1 for the traditional circuit. Vout is set to 4.0 volts and R2 is adjusted so the DC test voltage is at the center of its range. R2 is the only component adjusted since it is neglected for AC analysis.

There are negligible differences for the open loop gain and phase of the NCP100 with C3 compared to the TLV431 without C3 in the PNP circuit. Therefore there is no penalty with the added C3 in the NCP100 circuit.

If the PNP transistor is removed, the TLV431 open loop responses with and without C3 are very similar with a single pole roll–off. The pole appears to be near 4 Hz.

The NCP100 without the PNP has flat gain until a pole at 1.3 kHz due to R1 and C2. The plot remains at

-20 dB/decade and -90 degree phase margin until well beyond 100 kHz.

The overall gain of the feedback network can be limited due to R1, R3 and C2 in Figure 7. Varying these components will modify the maximum gain of the system.

Since the NCP100 provides a single pole roll–off, the MC33363B compensation pin will not provide this function. The feedback pin of the MC33363B is connected directly to the reference pin. This will keep the output of the error amp low. A diode is in series with the output of the op–amp allowing the compensation pin to directly control the feedback to the oscillator ramp. The compensation pin is connected to the feedback pin via a 2.7 k Ohm resistor. The collector of the optocoupler is also connected to the compensation pin and the emitter is grounded. This completes the design of the system. See Figure 14 for the board layout of the schematic in Figure 1 and Table 1 for the component values.

#### Results

Table A lists the system parameters. Figure A illustrates the single pole feedback from the circuit in Figure 1 and the layout in Figure 13. The output current step response has a negligible effect on the output voltage. Figure B is the output step response of the circuit from 20% to 100%. The circuit performance achieves the desired results for the off–line converter. The efficiency is low, but is expected for a low power off–line converter.

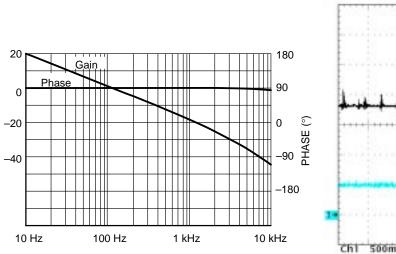


Figure 12. Gain and phase results from the 1.8 volt 1 ampere off–line converter.

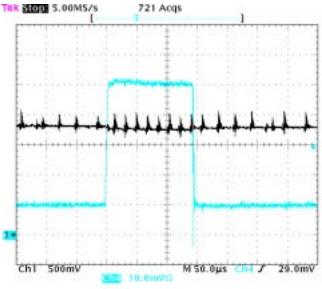


Figure 13. Output step response from 0.2 to 1.0 Amperes.

Parameter	Value
Operating Frequency	110 kHz
Primary Peak Current Limit	230 mA
Efficiency at 1.0 Ampere Load, 120 VACin	58.6 %
Efficiency at 1.0 Ampere Load, 230 VACin	57.2 %
Load Regulation, 120 VACin, 0.1 to 1.0 Ampere Load	22 mV
Line Regulation, 1.0 Ampere Load, 90 to 265 VACin	1 mV
Low Frequency Output Ripple, 1.0 Ampere Load	43 mVpp
High Frequency Output Ripple, 1.0 Ampere Load	350 mVpp

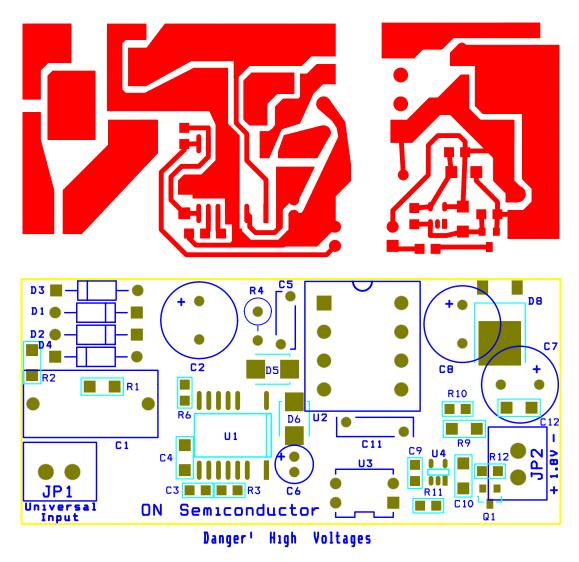


Figure 14. Layout of Off Line Power Supply

Table 2. Component	Values of Off-Line I	Power Supply
--------------------	----------------------	--------------

Reference	Part	Description	Manufacturer
C1	1 n	X Capacitor	
C2	4.7 u	400 Volt Bulk YK Series	Rubycon
C3	390 p	SMT Ceramic 0805	TDK
C4,C10,C12	1 u	SMT Ceramic 1206	TDK
C5	47 p	1 k Volt Ceramic Disc	
C6	10 u	25 Volt MS5 Series	Rubycon
C7,C8	820 u	6.3 Volt YXG Series	Rubycon
C9,C11	0.1 u	Y Capacitor	TDK
D1,D2,D3,D4	1N4005	Standard Recovery Rectifiers	ON Semiconductor
D5	MURS160T3	600 Volt Ultra Fast Rectifier	ON Semiconductor
D6	MURS120T3	200 Volt Ultra Fast Rectifier	ON Semiconductor
D7	MBRD835L	35 Volt Schottky Rectifier	ON Semiconductor
JP1,JP2		3.5 mm 2 Pole Connector	Wieland
Q1	BC858ALT1	Small Signal PNP	ON Semiconductor
R1,R2	4.7	SMT 0805	
R3	30 k	SMT 0805	
R4	3.9 k	1/4 Watt	
R6	2.7 k	SMT 0805	
R9	12 k	SMT 1206	
R10	7.5 k	SMT 0805	
R11	10	SMT 0805	
R12	120	SMT 0805	
U1	MC33363BDW	SMPS Controller with FET	ON Semiconductor
U2	Transformer	Transformer EE16 CTX22–14966	Coiltronics
U3	SFH615-4	4 pin Optocoupler	
U4	NCP100	Programmable Precision Reference	ON Semiconductor

#### References

- 1. Brown, Marty, <u>Power Supply Cookbook</u>, Newton, MA, Butterworth–Heinemann, 1994.
- 2. Basso, Christophe, Application Note: "AND8023: Implementing the NCP1200 in Low–Cost AC/DC Converters," ON Semiconductor, August, 2000.

# <u>Notes</u>

# <u>Notes</u>

# <u>Notes</u>

**ON Semiconductor** and without further notice to any products herein. SCILLC makes no warranty, representation or guarantee regarding the suitability of its products for any particular purpose, nor does SCILLC assume any liability arising out of the application or use of any product or circuit, and specifically disclaims any and all liability, including without limitation special, consequential or incidental damages. "Typical" parameters which may be provided in SCILLC data sheets and/or specifications can and do vary in different applications and actual performance may vary over time. All operating parameters, including "Typicals" must be validated for each customer application by customer's technical experts. SCILLC does not convey any license under its patent rights nor the rights of others. SCILLC products are not designed, intended, or authorized for use as components in systems intended for surgical implant into the body, or other applications intended to support or sustain life, or for any other application in which the failure of the SCILLC product could create a situation where personal injury or death may occur. Should Buyer purchase or use SCILLC products for any such unintended or unauthorized application, Buyer shall indemnify and hold SCILLC and its officers, employees, subsidiaries, affiliates, and distributors harmless against all claims, costs, damages, and expenses, and reasonable attorney fees arising out of, directly or indirectly, any claim of personal injury or death associated with such unintended or unauthorized use, even if such claim alleges that SCILLC was negligent regarding the design or manufacture of the part. SCILLC is an Equal Opportunity/Affirmative Action Employer.

#### PUBLICATION ORDERING INFORMATION

#### NORTH AMERICA Literature Fulfillment:

Literature Distribution Center for ON Semiconductor P.O. Box 5163, Denver, Colorado 80217 USA Phone: 303–675–2175 or 800–344–3860 Toll Free USA/Canada Fax: 303–675–2176 or 800–344–3867 Toll Free USA/Canada Email: ONlit@hibbertco.com Fax Response Line: 303–675–2167 or 800–344–3810 Toll Free USA/Canada

N. American Technical Support: 800–282–9855 Toll Free USA/Canada

EUROPE: LDC for ON Semiconductor – European Support

- German Phone: (+1) 303–308–7140 (Mon–Fri 2:30pm to 7:00pm CET) Email: ONlit–german@hibbertco.com French Phone: (+1) 303–308–7141 (Mon–Fri 2:00pm to 7:00pm CET)
- Email: ONlit-french@hibbertco.com English Phone: (+1) 303–308–7142 (Mon-Fri 12:00pm to 5:00pm GMT)
- Email: ONlit@hibbertco.com

EUROPEAN TOLL-FREE ACCESS\*: 00-800-4422-3781 \*Available from Germany, France, Italy, UK, Ireland

#### CENTRAL/SOUTH AMERICA:

Spanish Phone: 303–308–7143 (Mon–Fri 8:00am to 5:00pm MST) Email: ONlit–spanish@hibbertco.com Toll–Free from Mexico: Dial 01–800–288–2872 for Access –

then Dial 866–297–9322

ASIA/PACIFIC: LDC for ON Semiconductor – Asia Support Phone: 303–675–2121 (Tue–Fri 9:00am to 1:00pm, Hong Kong Time) Toll Free from Hong Kong & Singapore: 001–800–4422–3781 Email: ONlit–asia@hibbertco.com

JAPAN: ON Semiconductor, Japan Customer Focus Center 4–32–1 Nishi–Gotanda, Shinagawa–ku, Tokyo, Japan 141–0031 Phone: 81–3–5740–2700 Email: r14525@onsemi.com

ON Semiconductor Website: http://onsemi.com

For additional information, please contact your local Sales Representative.